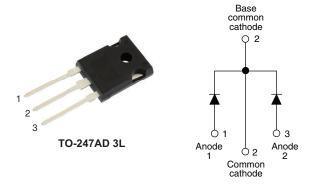


Ultrafast Soft Recovery Diode, 2 x 15 A FRED Pt® Gen 4



PRODUCT SUMMARY				
Package	TO-247AD 3L			
I _{F(AV)}	2 x 15 A			
V_{R}	600 V			
V _F at I _F	1.12 V			
t _{rr} typ.	See Recovery table			
T _J max.	175 °C			
Diode variation	Single die			

FEATURES

- Gen 4 FRED Pt® technology
- Low I_{RRM} and reverse recovery charge
- · Very low forward voltage drop
- Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow V_{F} , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Peak repetitive reverse voltage	V_{RRM}		600	V	
Average rectified forward current	I _{F(AV)}	T _C = 146 °C	15	А	
Non-repetitive peak surge current, per leg	I _{FSM}	$T_C = 25$ °C, $t_p = 8.3$ ms, half sine wave	200		
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	600	-	-		
Forward voltage		I _F = 15 A	-	1.32	1.55		
	V _F	I _F = 30 A	-	1.53	-	V	
		I _F = 15 A, T _J = 125 °C	-	1.17	-		
		I _F = 30 A, T _J = 125 °C	-	1.42	-		
		I _F = 15 A, T _J = 150 °C	-	1.12	1.28		
		I _F = 30 A, T _J = 150 °C	-	1.38	-		
Reverse leakage current	I _R	V _R = V _R rated	-	-	15		
		T _J = 125 °C, V _R = V _R rated	-	-	500	μΑ	
Junction capacitance	C _T	V _R = 600 V	-	16	-	pF	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Doverno recover time		T _J = 25 °C	$I_F = 15 \text{ A}$ $dI_F/dt = 1000 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	60	-	ns
Reverse recovery time	t _{rr}	T _J = 125 °C		-	83	-	
Deels veessans assured	eak recovery current I _{RRM}	T _J = 25 °C		-	13	-	Α
Feak recovery current		T _J = 125 °C		-	21	-	
Reverse recovery charge Q _{rr}		T _J = 25 °C		-	500	-	nC
	T _J = 125 °C		-	1100	-	110	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R _{thJC}		-	-	1.4	°C/W
Thermal resistance, case to heat sink	R _{thCS}		-	0.4	-	
Maiabt			-	6.0	-	g
Weight			-	0.21	-	oz.
Mounting torque			6.0	_	12	kgf · cm
			(5)	_	(10)	(lbf \cdot in)
Marking device		Case style TO-247AD 3L	C4PU3006L			

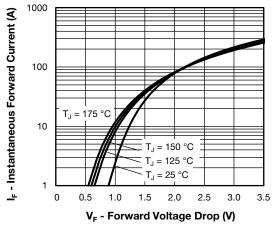


Fig. 1 - Typical Forward Voltage Drop Characteristics

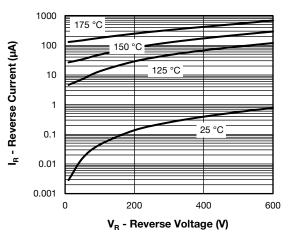


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

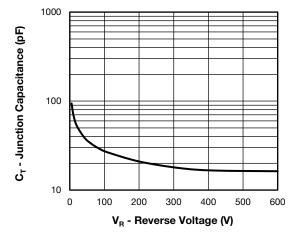


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

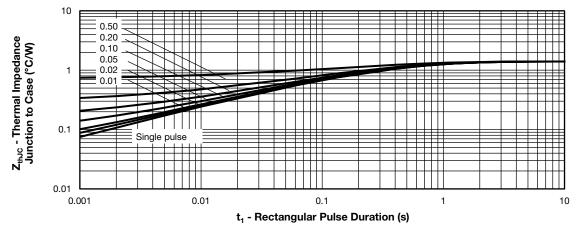


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

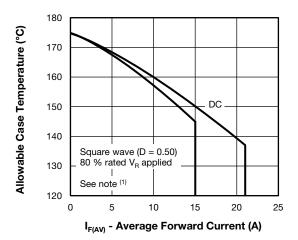


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

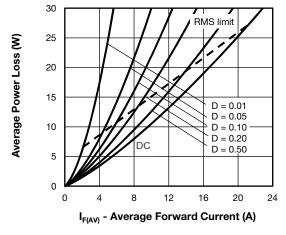


Fig. 6 - Forward Power Loss Characteristics

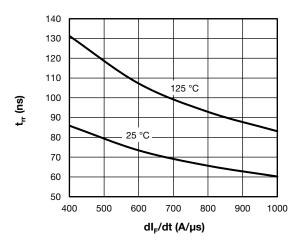


Fig. 7 - Typical Reverse Recovery Time vs. dI_{F}/dt

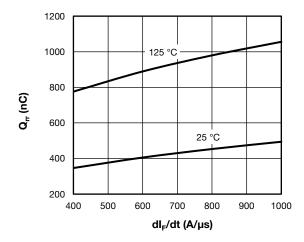


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see Fig.5)} \\ P_{dREV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D); } I_R \ \text{at } V_R = \text{rated } V_R \\ \end{array}$

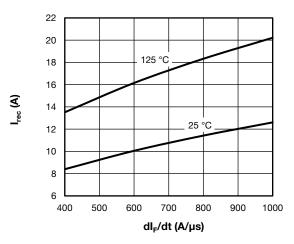
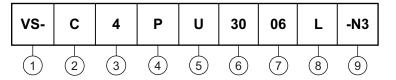


Fig. 9 - Typical Reverse Current vs. dl_F/dt

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

C = common diode

3 - FRED Pt Gen 4

4 - P = TO-247 package

5 - Process type:

U = ultrafast recovery

6 - Current rating (30 = 2 x 15 A)

7 - Voltage rating (06 = 600 V)

8 - Package: L = long lead

9 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-C4PU3006L-N3	25	500	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions TO-247AD 3L <u>www.vishay.com/doc?95626</u>				
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007		



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below:

D91A DA24F4100L DD89N1600K-A DD89N16K-K RL252-TP DSEI2X30-06C 1N4005-TR BAV199-TP UFS120Je3/TR13

JANS1N6640US DD89N16K DD89N16K-A 481235F 067907F MS306 ND104N08K SPA2003-B-D-A01 US2JFL-TP UFS105Je3/TR13

A1N5404G-G ACGRA4007-HF ACGRB207-HF RF301B2STL RF501B2STL UES1302 BAV199E6433HTMA1 ACGRC307-HF

ACEFC304-HF JANTXV1N5660A UES1106 GS2K-LTP D126A45C D251N08B SCHJ22.5K SM100 SCPA2 SDHD5K STTH20P035FP

VS-8EWS12S-M3 VS-12FL100S10 ACGRA4001-HF MUR420GP-TP 1N5404GP-E3/54 ND89N08K D1821SH45T PR D1251S45T

JANTX1N3890 SKN20/16 SKN70/16 1N3660R